

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L10	863788	@ad>"20040318"@rad>"20040318"@pt1ch>"20040318"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:43
L11	2169	(cobalt co titanium ti nickel nickel ni tantalum ta) adj (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N" "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N" "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj (cobalt co titanium ti nickel nickel ni tantalum ta) not L10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:33
L12	148	(tungsten adj nitride wn) adj (tungsten w) adj (silicon adj nitride "S.sub.3N.sub.4") not L10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:17
L13	2	L11 and L12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:43
L14	295	(tungsten adj nitride wn) adj (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not L10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:17
L15	2	L11 and L14 not L13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:43
L16	1153	(tungsten adj nitride wn) with (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not L10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:16
L17	77	L11 and L16 not (L13 L15)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:43
L19	24	17 not encapsulating adj cu	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:44
L20	6304	metal adj gate not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:51
L21	9	12 and 20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:52
L22	9	(cobalt co titanium ti nickel nickel ni tantalum ta barrier) and 21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:27
L23	11990	ultra adj thin not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:13
L24	612	(ti titanium) adj (titanium adj nitride tin) adj (ti titanium) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:00
L25	22	24 and 23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:14
L26	1153	(tungsten adj nitride wn) with (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not L10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:14
L27	3	25 and 26	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:16
L29	57	24 and 26	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:17

L30	0	29 and 20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:17
L31	940572	gate not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:17
L33	3	29 and 31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:18
L34	58	12 and 31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:26
L35	58	(cobalt co titanium ti nickel nickel ni tantalum ta barrier) and 34	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:27
L39	65	(*4490209* *4505028* *4505082* *4684542* *4847111* *4977100* *5066615* *5077691* *5132756* *5200028* *5341016* *5342798* *5364803* *5470773* *5559047* *5600177* *5633212* *5691235* *5716881* *5789294* *5854096* *5925918* *5962904* *6020111* *6096640* *6107171* *6197702* *6265297* *6284634* *6323115* *6326248* *6348380*)PN OR (*2002/0137284* *2002/0137321* *2004/0014330* *2004/0132272* *5888588* *6346467* *6764961* *6960515*).URPN	US-PGPUB; USPAT; USOCR	OR	ON	2005/12/09 11:49
L40	8	39 and 26 not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:50
L41	73	24 with (tungsten adj nitride wn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:05
L42	60	(polycrystalline poly adj silicon polysilicon silicon si doped) with 41	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:07
L44	8	42 not encapsulating adj cu	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:03
L45	92	24 with (wn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:05
L46	99	encapsulating adj cu	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:06
L47	40	45 not 46	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:27
L49	234	wn adj w not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:29
L50	1087	(co ti ni ta) adj (tin *ni.sub.3n* *ni.sub.3n.sub.2* *co.sub.2n* *co.sub.3n.sub.2* tan) adj (co ti ni ta) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:05
L51	9	49 and 50	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:33
L52	1	five adj layer with (cobalt co titanium ti nickel nickel ni tantalum ta) and (titanium adj nitride TiN nickel adj nitride *Ni.sub.3N* *Ni.sub.3N.sub.2* cobalt adj nitride *Co.sub.2N* *Co.sub.3N.sub.2* tantalum adj nitride TaN) and (tungsten w) and (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 13:03
L54	47	five adj layer and (cobalt co titanium ti nickel nickel ni tantalum ta) and (titanium adj nitride TiN nickel adj nitride *Ni.sub.3N* *Ni.sub.3N.sub.2* cobalt adj nitride *Co.sub.2N* *Co.sub.3N.sub.2* tantalum adj nitride TaN) and (tungsten w) and (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:37

L55	49	(five with layer with (barrier adhesion)) and (cobalt co titanium ti nickel nickel ni tantalum ta) and (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N" "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N" "Co.sub.3N.sub.2" tantalum adj nitride TaN) and (tungsten w) and (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:40
L56	29776	(co ti ni ta) with (tin "ni.sub.3n" "ni.sub.3n.sub.2" "co.sub.2n" "co.sub.3n.sub.2" tan) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 13:12
L57	223	50 with (tungsten adj nitride wn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 12:43
L58	83	gate and 57	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 13:03
L59	22	four adj layer with (cobalt co titanium ti nickel nickel ni tantalum ta) and (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N" "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N" "Co.sub.3N.sub.2" tantalum adj nitride TaN) and (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 13:04
L60	1816	(co ti ni ta) with (tin "ni.sub.3n" "ni.sub.3n.sub.2" "co.sub.2n" "co.sub.3n.sub.2" tan) with (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:12
L61	1003	60 with (barrier adhesion)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 13:13
L63	2074913	(polycrystalline poly adj silicon polysilicon silicon si doped) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:07
L64	290	61 with 63	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:08
L65	88	gate and 64	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:08
L68	1995	63 with (titanium ti) with (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:14
L71	1832	63 with (titanium adj nitride ti) with (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:24
L72	767	16 and 71	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:16
L73	214	14 and 71	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:17
L75	121	12 and 71	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:18
L76	9	12 and 20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:22
L78	131	68 and 12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:26
L79	0	si adj ti adj wn	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:26

L80	11	63 adj (titanium adj nitride tin) adj (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:32
L81	2	(*6,617,624*).PN	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/09 14:29
L82	891	(barrier adhesion) with (titanium adj nitride tin) adj (tungsten adj nitride wn) not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:33
L83	0	(barrier adhesion) with tinwn not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:33
L87	20	(barrier with adhesion) with tin adj wn not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 14:36
L88	145888	liquid adj phase not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:12
L89	24	(US-20040106274-\$ or US-20040132272-\$ or US-20040014330-\$ or US-20020084192-\$ or US-20020137321-\$ or US-20020098670-\$ or US-20040106279-\$ or US-20020137284-\$ or US-20050184397-\$ or US-20030045068-\$ or US-20020111025-\$ or US-20020024119-\$ or US-20020127888-\$).did. or (US-6960515-\$ or US-6764961-\$ or US-5888588-\$ or US-6346467-\$ or US-6323115-\$ or US-6197702-\$ or US-6720604-\$ or US-6358790-\$ or US-6790723-\$ or US-6333547-\$). did. or (KR-2003087131-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2005/12/09 16:14
L90	1	88 and 89	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:15
L91	92	liquid adj phase adj oxide not 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:23
L92	5	sidewall with 91	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:16
L94	0	92 and (silicon adj nitride "S.sub.3N.sub.4")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:23
L95	0	91 with (silicon adj nitride "S.sub.3N.sub.4")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:18
L96	23	91 and (silicon adj nitride "S.sub.3N.sub.4")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:22
L97	69909	oxide with (silicon adj nitride "S.sub.3N.sub.4")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:24
L98	12	97 and 89	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:52
L99	5	*665122*.ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:56
L100	6	(*4505028*"*6245605*"*6277722*).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 16:56
L101	1	liquid adj phase adj oxide with wet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 18:14

L104	26	(US-20040106274-\$ or US-20040132272-\$ or US-20040014330-\$ or US-20020084192-\$ or US-20020137321-\$ or US-20020098670-\$ or US-20040106279-\$ or US-20020137284-\$ or US-20050184397-\$ or US-20030045068-\$ or US-20020111025-\$ or US-20020024119-\$ or US-20020127888-\$).did. or (US-6960515-\$ or US-6764961-\$ or US-5888588-\$ or US-6346467-\$ or US-6323115-\$ or US-6197702-\$ or US-6720604-\$ or US-6358790-\$ or US-6790723-\$ or US-6333547-\$ or US-6277722-\$ or US-6245605-\$).did. or (KR-2003087131-\$).did.	US-PGPUB; USPAT; DERWENT	OR	ON	2005/12/09 18:26
L105	16	dop\$ and 104	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 18:26
L106	11	(US-20040132272-\$ or US-20040014330-\$ or US-20020137321-\$ or US-20020137284-\$ or US-20020111025-\$ or US-20020127888-\$).did. or (US-6960515-\$ or US-6764961-\$ or US-6346467-\$ or US-6277722-\$ or US-6245605-\$).did.	US-PGPUB; USPAT	OR	ON	2005/12/09 19:36
L107	0	(metal adj gate and gate adj oxide adj layer and silicon and doped adj silicon adj layer and stacked and metal adj barrier and tungsten adj nitride adj layer and tungsten and silicon adj nitride adj cap adj layer). clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 19:53
S1	863788	@ad> "20040318" @rlad> "20040318" @pt1d> "20040318"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 20:33
S2	2	("20050205942").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/09 19:51
S4	60101	gate adj oxide not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:08
S16	0	((cobalt co titanium ti nickel nickel ni tantalum ta) not (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2". cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj ((cobalt co titanium ti nickel nickel ni tantalum ta) not (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN)) adj (tungsten adj nitride wn) adj (tungsten w) adj (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:50
S17	0	((cobalt co titanium ti nickel nickel ni tantalum ta) not (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj10 (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj10 ((cobalt co titanium ti nickel nickel ni tantalum ta) not (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN)) adj10 (tungsten adj nitride wn) adj10 (tungsten w) adj10 (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:50
S18	0	((cobalt co titanium ti nickel nickel ni tantalum ta) not (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN)) with (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) with ((cobalt co titanium ti nickel nickel ni tantalum ta) not (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN)) with (tungsten adj nitride wn) with (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:52
S19	764	(cobalt co titanium ti nickel nickel ni tantalum ta) with (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) with (cobalt co titanium ti nickel nickel ni tantalum ta) with (tungsten adj nitride wn) with (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 11:26
S20	18	(cobalt co titanium ti nickel nickel ni tantalum ta) adj100 (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj "100" (cobalt co titanium ti nickel nickel ni tantalum ta) adj100 (tungsten adj nitride wn) adj100 (tungsten w) adj100 (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:54
S21	1	S4 and S20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:53
S23	2169	(cobalt co titanium ti nickel nickel ni tantalum ta) adj (titanium adj nitride TiN nickel adj nitride "Ni.sub.3N". "Ni.sub.3N.sub.2" cobalt adj nitride "Co.sub.2N". "Co.sub.3N.sub.2" tantalum adj nitride TaN) adj (cobalt co titanium ti nickel nickel ni tantalum ta) not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:58
S24	148	(tungsten adj nitride wn) adj (tungsten w) adj (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 22:00
S25	2	S23 and S24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 21:58
S26	295	(tungsten adj nitride wn) adj (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 22:08

S27	2	S23 and S26 not S25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 22:00
S28	1153	(tungsten adj nitride wn) with (tungsten w) with (silicon adj nitride "S.sub.3N.sub.4") not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 22:08
S29	77	S23 and S28 not (S25 S27)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/09 10:43